

EVEREST^{pico}TM 1 μ m Picosecond Fiber Laser AP-1030P

Applications:

- Laser cutting, drilling and scribing (glass, sapphire, silicon, silicon carbide, ceramics, nitinol stents, CFRP, PCD and CVD diamond)
- Laser thin film patterning (TCO, metal, thin film solar cells)
- 2.5D surface shaping (metals, ceramics, plastics)
- Laser marking (glass, sapphire, silicon carbide, silicon, metals, plastics)

Features:

- Picosecond pulses
- High pulse energy and peak power
- High repetition rate capability
- Near diffraction limited beam quality
- Rugged OEM package and compact size



Optical Characteristics:

| Parameter | Specification |
|------------------------------|-------------------------|
| Operation mode | Pulsed |
| Operating wavelength | 1030 nm |
| Average power | 15 W, 30 W, 60 W, 100 W |
| Pulse energy | 30 μ J, 50 μ J |
| Pulse width | 50 ps |
| Beam quality, M ² | < 1.3 |
| Output power stability | Within \pm 5% |
| Output delivery | Collimated output beam |

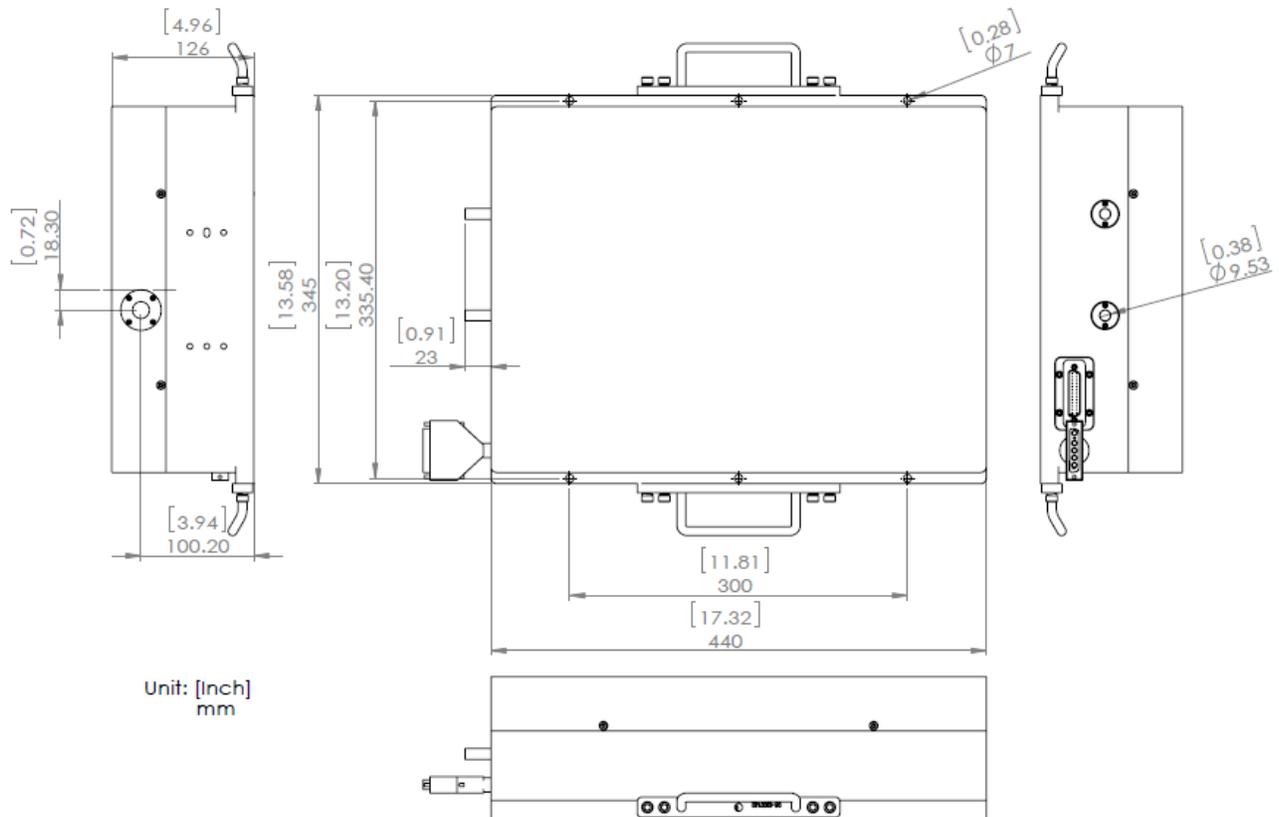
(For custom requirements, please contact AdValue Photonics)

Specifications subject to change without notice

General Characteristics:

| Parameter | Specification |
|-----------------------|--|
| Operating temperature | 10 to +30 °C |
| Storage temperature | +5 to +70 °C |
| Cooling | Water cooled (portable recirculating chiller available as an option) |
| Power requirement | AC 100~240 V (50/60Hz) (operating with AdValue Photonics Control Unit) |
| Warm-up time | 10 minutes |
| Package dimensions | 345(W) x 440(D) x 126(H) mm |

Mechanical Outline:



Ordering Information:

Part Number: AP - 1030P - xx - xxx

Standard Wavelength:
1030 = 1030 nm

Output Power:
15 = 15 W
xx = xx W

Pulse Energy:
030 = 30 μJ
xxx = xxx μJ

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